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# 200mA, SMD Switching Diode

### FEATURES

- Designed for mounting on small surface
- Low Capacitance
- Low forward voltage drop
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

### **MECHANICAL DATA**

• Case: SOT-23

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- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test

• Weight: 8 mg (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F</sub>	200	mA	
V <sub>RRM</sub>	100	V	
I <sub>FSM</sub>	2	А	
V <sub>F</sub> at I <sub>F</sub> =10mA	1	V	
Т <sub>Ј</sub> Мах.	150	°C	
Package	SOT-23		





<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	VALUE	UNIT	
	MMBD	4148		5D	
Marking code on the device	MMBD4148CA			A1	
	MMBD	4148CC		A4	
	MMBD4148SE			A7	
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Forward current		I <sub>F</sub>	200	mA	
Repetitive peak forward surge current		I <sub>FRM</sub>	700	mA	
Non-repetitive peak forward surge current at t=1µs at t=1s			2	А	
		at t=1s	I <sub>FSM</sub>	1	A
Junction temperature range			TJ	-55 to +150	°C
Storage temperature range			T <sub>STG</sub>	-55 to +150	°C





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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-ambient thermal resistance	R <sub>eja</sub>	357	°C/W

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS SYMBOL		MIN	MAX	UNIT	
Forward voltage per diode (1)	I <sub>F</sub> = 10mA, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	1.0	V	
	V <sub>R</sub> = 20V ,T <sub>J</sub> = 25°C		-	25.0	nA	
Reverse current per diode <sup>(2)</sup>	V <sub>R</sub> = 75V ,T <sub>J</sub> = 25°C	I <sub>R</sub>	-	5.0	μA	
	V <sub>R</sub> = 20V ,T <sub>A</sub> = 150°C		-	50.0		
	I <sub>R</sub> = 5μΑ ,T <sub>J</sub> = 25°C	N	75	-	V	
Reverse breakdown voltage	I <sub>R</sub> = 100μΑ ,T <sub>J</sub> = 25°C	V <sub>(BR)</sub>	100	-		
Junction capacitance f= 1MHz, V <sub>R</sub> =0V		CJ	-	4.0	pF	
$ \begin{array}{c} \mbox{Reverse recovery time} & I_F = 10 \mbox{mA}, I_R = 1 \mbox{mA}, \\ \mbox{R}_L = 100 \mbox{\Omega}, V_R = 6 \mbox{V} \end{array} $		t <sub>rr</sub>	-	4.0	ns	

#### Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

ORDERING INFORMATION			
ORDERING CODE (Note 1)	PACKAGE	PACKING	
MMBD414xx RFG	SOT-23	3K / 7" Reel	
MMBD414xx R5G	SOT-23	10K / 13" Reel	

#### Note:

1. "xx" defines part no. from "8" to "8SE"



### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

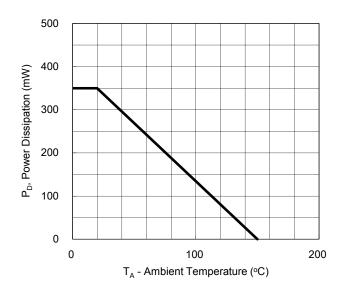


Fig. 1 Power Derating Curve

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#### **Fig.2 Forward Characteristics**

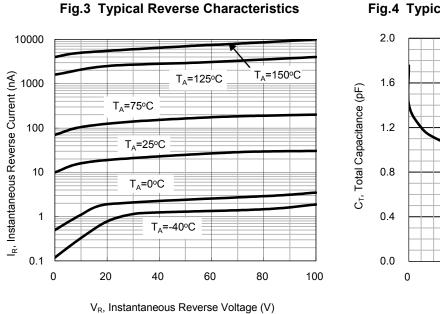
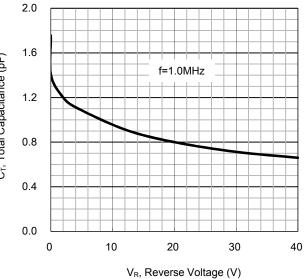


Fig.4 Typical Capacitance vs. Reverse Voltage

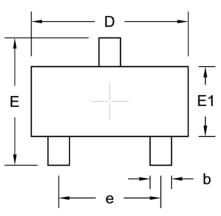


# MMBD4148/CA/CC/SE

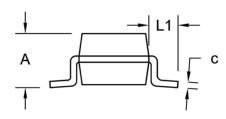
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## PACKAGE OUTLINE DIMENSION

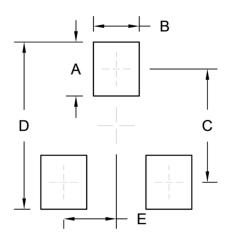




DIM.	Unit (mm) Min. Max.		Unit (	(inch)
			Min.	Max.
A	0.89	1.12	0.035	0.044
b	0.30	0.50	0.012	0.020
с	0.08	0.20	0.003	0.008
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E1	1.20	1.40	0.047	0.055
е	1.90 BSC		0.07	5 BSC
L1	0.54 REF.		0.021	I REF.

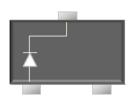


## SUGGEST PAD LAYOUT

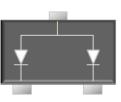


Symbol	Unit (mm)	Unit (inch)
A	1.00	0.039
В	0.85	0.033
С	2.10	0.083
D	3.10	0.122
E	0.98	0.039

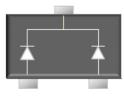
### **PIN CONFIGURATION**



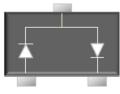
MMBD4148



MMBD4148CA



MMBD4148CC





# MMBD4148/CA/CC/SE

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